AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s): Tsukasa YAJIMA							Docket No. PNET.009D	
Serial No. 09/768,271		Filing Date January 25, 2001		Examiner A. Mai			Group Art Unit 2814	
Invention, PSEM	C	CTOR DEVIC	E HAVING PRO	TECTIVE LA	YER ON FI	ELD OX	IDE	
Transmitted herev	vith is an	amendment in		fied application		NTS:		
			CLAIMS A	AS AMENDED	)		п	
	CLAIMS REMAINING		HIGHEST #	NUMB	ER EXTRA	RAT	E	ADDITIONAL
	AFTER A	AMENDMENT	PREV. PAID FO	R CLAIMS	PRESENT			FEE
TOTAL CLAIMS	9	-	20		0	-	18.00	\$0.00
INDEP. CLAIMS	P. CLAIMS 2 -			= 0 x		x \$8	34.00	\$0.00
Multiple Dependent Claims (check if applicable)  TOTAL ADDITIONAL FEE FOR THIS AMENDMENT								\$0.00 \$0.00
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ANDREW J. TI REG. NO. 33,58  VOLENTINE F 12200 SUNRISI RESTON, VA TEL. NO.: (703)	ELESZ, JI ELESZ, JI ERANCOS E VALLE 20191	S, P.L.L.C. Y DRIVE, SUI	TE 150		on first class m Assistant C 20231.	ail under (commission)	with B7 C.F.R. ner for F	and fee is being deposited the U.S. Postal Service as 1.8 and is addressed to the Patents, Washington, D.C. ling Correspondence



PNET.009D

## THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of

Tsukasa Yajima

Group Art Unit: 2814

Serial No.: 09/768,274

Examiner: A. Mai

Filed: January 25, 2001

For: SEMICONDUCTOR DEVICE HAVING PROTECTIVE LAYER ON FIELD OXIDE

(As Amended)

## **AMENDMENT**

Honorable Assistant Commissioner for Patents Washington, D.C. 20231

Date: December 31, 2001

Sir:

In response to the Office Action dated October 12, 2001, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

## In the Claims:

Please cancel claims 4, 5 and 10 without prejudice or disclaimer of the subject matter contained therein.

The following replacement claims are respectfully submitted:

6. (Amended) A semiconductor device comprising:

first and second gates formed on active regions of a substrate;

a field oxide formed on the substrate between said first and second gates;